Variant: 001 Generated: 12/19/2017 7:15:00 AM

TID #: TIDA-01553

## TIDA-01553 REV B Bill of Materials



Item #	Designator	Quantity	Value	PartNumber	Manufacturer	Description	PackageReference
1	!PCB	1		TIDA-01553	Any	Printed Circuit Board	
2	C1	1	470pF	GCM155R71H471KA37D	MuRata	CAP, CERM, 470 pF, 50 V, +/- 10%, X7R, AEC-Q200 Grade 1, 0402	0402
3	C2	1	10uF	GRM21BZ71E106KE15L	MuRata	CAP, CERM, 10 μF, 25 V,+/- 10%, X7R, 0805	0805
4	C3, Cx2	2	0.47uF	GRM21BR71H474KA88L	MuRata	CAP, CERM, 0.47 µF, 50 V, +/- 10%, X7R, 0805	0805
5	C3a, C3b, C3c, C3d	4	68uF	50SVPF68M	Panasonic	CAP, Aluminum Polymer, 68 µF, 50 V, +/- 20%, 0.02 ohm, F12, SMD, 2 Leads, Body 10.5x10.5mm, Height 12.7mm SMD	Body 10.5x10.5mm Height 12.7mm
6	C4, C5, C6, C7, C8, C9, C10, C11	8	4.7uF	GRM31CR71H475KA12L	MuRata	CAP, CERM, 4.7 µF, 50 V, +/- 10%, X7R, 1206	1206
7	C12	1	0.22uF	GRM188R71H224KAC4D	MuRata	CAP, CERM, 0.22 µF, 50 V, +/- 10%, X7R, 0603	0603
8	C13, C18	2	100pF	GRM1555C1H101JA01D	MuRata	CAP, CERM, 100 pF, 50 V, +/- 5%, C0G/NP0, 0402	0402
9	C14	1	2200pF	GRM155R71E222KA01D	MuRata	CAP, CERM, 2200 pF, 25 V, +/- 10%, X7R, 0402	0402
10	C15	1	0.01uF	GRM155R71E103KA01D	MuRata	CAP, CERM, 0.01 µF, 25 V, +/- 10%, X7R, 0402	0402
11	C16	1	1uF	GRM21BR71H105KA12L	MuRata	CAP, CERM, 1 µF, 50 V,+/- 10%, X7R, 0805	0805
12	C17, C46	2	0.01uF	GRM155R71H103KA88D	MuRata	CAP, CERM, 0.01 µF, 50 V, +/- 10%, X7R, 0402	0402
13	C19, C20, C21,	12	10uF	GCM32ER71E106KA57L	MuRata	CAP, CERM, 10 µF, 25 V, +/- 10%, X7R, AEC-Q200 Grade 1, 1210	1210
13	C22, C23, C24, C31, C32, C33, C36, C37, C38	12	Tour	GOWGZERVIETOORASYE	iviurata	CAP, CERWI, 10 JII., 23 V, 77- 10/6, ANY, AEC-2200 Glade 1, 1210	1210
14	C25, C28, C29, C30, C39, C44, C45	7	0.1uF	GRM155R71H104ME14D	MuRata	CAP, CERM, 0.1 μF, 50 V,+/- 20%, X7R, 0402	0402
15	C26, C27	2	2.2uF	GRM188R71A225KE15D	MuRata	CAP, CERM, 2.2 µF, 10 V,+/- 10%, X7R, 0603	0603
16	C34, C35	2	270uF	APSG160ELL271MH06S	Chemi-Con	CAP, Aluminum Polymer, 270 µF, 16 V, +/- 20%, 0.022 ohm, TH	D8xL6mm
17	C40, C41	2	33pF	GRM1555C1H330JA01D	MuRata	CAP, CERM, 33 pF, 50 V,+/- 5%, C0G/NP0, 0402	0402
18	C42	1	470pF	GRM155R71H471KA01D	MuRata	CAP, CERM, 470 pF, 50 V,+/- 10%, X7R, 0402	0402
19	C43	1	4700pF	GRM155R71H472KA01D	MuRata	CAP, CERM, 4700 pF, 50 V,+/- 10%, X7R, 0402	0402
20	C47	1	0.022uF	GRM155R71H223KA12D	MuRata	CAP, CERM, 0.022 µF, 50 V,+/- 10%, X7R, 0402	0402
21	C48	1	2.2uF	GRM31CR71H225KA88L	MuRata	CAP, CERM, 2.2 µF, 50 V,+/- 10%, X7R, 1206	1206
22	C49, C50	2	0.1uF	GRM188R71H104KA93D	MuRata	CAP, CERM, 0.1 µF, 50 V, +/- 10%, X7R, 0603	0603
23	C54	1	0.047uF	GRM155R71E473KA88D	MuRata	CAP, CERM, 0.047 µF, 25 V,+/- 10%, X7R, 0402	0402
24	Cx1	1	2000uF	B41605A8208M002	TDK	CAP, AL, 2000 μF, 63 V, +/- 20%, 0.035 ohm, AEC-Q200 Grade 1, TH	D22xL40mm
25	D1, D3, D4	3	60V	PMEG6010CEJ,115	NXP Semiconductor	Diode, Schottky, 60 V, 1 A, SOD-323F	SOD-323F
26	D2	1	5.6V	MMSZ4690T1G	ON Semiconductor	Diode, Zener, 5.6 V, 500 mW, SOD-123	SOD-123
27	D5	1	36V	SMAJ36CA	Littelfuse	Diode, TVS, Bi, 36 V, SMA	SMA
28	Dx1	1	100V	PMEG10010ELRX	NXP Semiconductor	Diode, Schottky, 100 V, 1 A, AEC-Q101, SOD-123W	SOD-123W
29	Dx2	1	75V	BAS16W-7-F	Diodes Inc.	Diode, Switching, 75 V, 0.15 A, SOT-323	SOT-323
30	J1, J2	2		CB35-36-CY	Panduit	Terminal 50A Lug	CB35-36-CY
31	J3, J4, J5, J6	4		575-8	Keystone	Standard Banana Jack, Uninsulated, 8.9mm	Keystone575-8
32	J7	1		68001-403HLF	FCI	Header, 2.54mm, 3x1, Tin, TH	Header, 2.54mm, 3x1, TH
33	L1 L2, L3	1 2	700nH 3.3uH	7443630070 IHLP5050EZER3R3M01	Wurth Elektronik	Inductor, Shielded Drum Core, Mn-Zn, 700 nH, 32 A, 0.000829 ohm, SMD Inductor, Shielded Drum Core, Powdered Iron, 3.3 µH, 15 A, 0.0077	21.8x14.5x21.5mm IHLP-5050EZ
34	Q1, Q2, Q3, Q4,	7	40V	SQJ886EP-T1-GE3	Vishay-Dale Vishay-Siliconix	ohm, SMD  MOSFET, N-CH, 40 V, 60 A, PowerPAK_SO-8L	PowerPAK SO-8L
36	Q5, Q6, Q8 Qx1	1	45 V	BC847BW,115	NXP Semiconductor	Transistor, NPN, 45 V, 0.1 A, AEC-Q101, SOT-323	SOT-323
37	R1	1	10.0	CRCW120610R0FKEA	Vishay-Dale	RES, 10.0, 1%, 0.25 W, 1206	1206
38	R2, R3	2	0.002	ERJ-M1WTF2M0U	Panasonic	RES, 0.002, 1%, 1 W, 2512	2512
39	R4, R5, R7, R9	4	100	RG1005P-101-B-T5	Susumu Co Ltd	RES, 100, 0.1%, 0.063 W, 0402	0402
40	R6	1	2.49k	CRCW25122K49FKEG	Vishay-Dale	RES, 2.49 k, 1%, 1 W, AEC-Q200 Grade 0, 2512	2512
41	R8, R30, R31	3	49.9	CRCW040249R9FKED	Vishay-Dale	RES, 49.9, 1%, 0.063 W, 0402	0402
42	R10	1	40.2k	CRCW040240K2FKED	Vishay-Dale	RES, 40.2 k, 1%, 0.063 W, 0402	0402
43	R11	1	280k	CRCW0402280KFKED	Vishay-Dale	RES, 280 k, 1%, 0.063 W, 0402	0402
44	R12	1	8.25k	CRCW04028K25FKED	Vishay-Dale	RES, 8.25 k, 1%, 0.063 W, 0402	0402
45	R13, R16, R19, R20, R29, R32, R33, R34, R36, R47, R52, R53	12	0	CRCW04020000Z0ED	Vishay-Dale	RES, 0, 5%, 0.063 W, 0402	0402
46	R14	1	4.75k	CRCW04024K75FKED	Vishay-Dale	RES, 4.75 k, 1%, 0.063 W, 0402	0402
47	R15	1	93.1k	CRCW040293K1FKED	Vishay-Dale	RES, 93.1 k, 1%, 0.063 W, 0402	0402
48	R17	1	48.7k	CRCW040248K7FKED	Vishay-Dale	RES, 48.7 k, 1%, 0.063 W, 0402	0402
49	R18	1	18.7k	CRCW040218K7FKED	Vishay-Dale	RES, 18.7 k, 1%, 0.063 W, 0402	0402
50	R21, R22, R27, R28, R44, R45	6	10.0	CRCW060310R0FKEA	Vishay-Dale	RES, 10.0, 1%, 0.1 W, 0603	0603
51	R23, R24	2	0	CRCW06030000Z0EA	Vishay-Dale	RES, 0, 5%, 0.1 W, 0603	0603
52	R25, R26	2	0.003	PA2512FKF070R003E	Yageo America	RES, 0.003, 1%, 1 W, AEC-Q200 Grade 0, 2512	2512
53	R35, R40, R41	3	10.0k	CRCW040210K0FKED	Vishay-Dale	RES, 10.0 k, 1%, 0.063 W, 0402	0402
54	R43, R46	2	100k	CRCW0805100KFKEA	Vishay-Dale	RES, 100 k, 1%, 0.125 W, 0805	0805
55	R49	1	10k	CRCW040210K0JNED	Vishay-Dale	RES, 10 k, 5%, 0.063 W, 0402	0402
56	R50	1	4.99k	CRCW04024K99FKED	Vishay-Dale	RES, 4.99 k, 1%, 0.063 W, 0402	0402
57	R51	1	2.21k	CRCW04022K21FKED	Vishay-Dale	RES, 2.21 k, 1%, 0.063 W, 0402	0402
58	Rx1	1	10k	CRCW120610K0JNEA	Vishay-Dale	RES, 10 k, 5%, 0.25 W, 1206	1206
59	TP1, TP4, TP9, TP10, TP13	5		5010	Keystone	Test Point, Multipurpose, Red, TH	Red Multipurpose Testpoint
60	TP2, TP3, TP6, TP8 TP5, TP7, TP11,	5		5012	Keystone Keystone	Test Point, Multipurpose, White, TH  Test Point, Multipurpose, Black, TH	White Multipurpose Testpoint Black Multipurpose
	TP12, TP14 U1	1		LM25122QPWPTQ1	Texas Instruments	Automotive Grade, 3-42V Wide Vin, Synchronous Boost Controller with	Testpoint PWP0020A
62	U2	1		LM5140QRWGRQ1	Texas Instruments	Multiphase Capability, PWP0020A (TSSOP-20)  Wide Vin Dual 2.2MHz low lq Synchronous Buck Controller, RWG0040A	
62		l	1			(VQFNP-40)  Low lo Always ON Smart Diode Controller, DBV0006A (SOT-23-6)	
63		4		LM747000DBV/TO4			
63 64	U3	1	22005	LM74700QDBVTQ1	Texas Instruments		DBV0006A
63 64 65	U3 C51, C52, C53	0	330pF	GRM188R71H331KA01D	MuRata	CAP, CERM, 330 pF, 50 V, +/- 10%, X7R, 0603	0603
63 64 65 66	U3 C51, C52, C53 C55	0	2.2uF	GRM188R71H331KA01D GRM31CR71H225KA88L	MuRata MuRata	CAP, CERM, 330 pF, 50 V, +/- 10%, X7R, 0603 CAP, CERM, 2.2 µF, 50 V,+/- 10%, X7R, 1206	0603 1206
63	U3 C51, C52, C53	0	330pF 2.2uF 10.0	GRM188R71H331KA01D	MuRata	CAP, CERM, 330 pF, 50 V, +/- 10%, X7R, 0603	0603

## IMPORTANT NOTICE FOR TI DESIGN INFORMATION AND RESOURCES

Texas Instruments Incorporated ("TI") technical, application or other design advice, services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using any particular TI Resource in any way, you (individually or, if you are acting on behalf of a company, your company) agree to use it solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources.

You understand and agree that you remain responsible for using your independent analysis, evaluation and judgment in designing your applications and that you have full and exclusive responsibility to assure the safety of your applications and compliance of your applications (and of all TI products used in or for your applications) with all applicable regulations, laws and other applicable requirements. You represent that, with respect to your applications, you have all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. You agree that prior to using or distributing any applications that include TI products, you will thoroughly test such applications and the functionality of such TI products as used in such applications. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

You are authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING TI RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY YOU AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

You agree to fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of your non-compliance with the terms and provisions of this Notice.

This Notice applies to TI Resources. Additional terms apply to the use and purchase of certain types of materials, TI products and services. These include; without limitation, TI's standard terms for semiconductor products <a href="http://www.ti.com/sc/docs/stdterms.htm">http://www.ti.com/sc/docs/stdterms.htm</a>), evaluation modules, and samples (<a href="http://www.ti.com/sc/docs/sampterms.htm">http://www.ti.com/sc/docs/sampterms.htm</a>).

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2018, Texas Instruments Incorporated